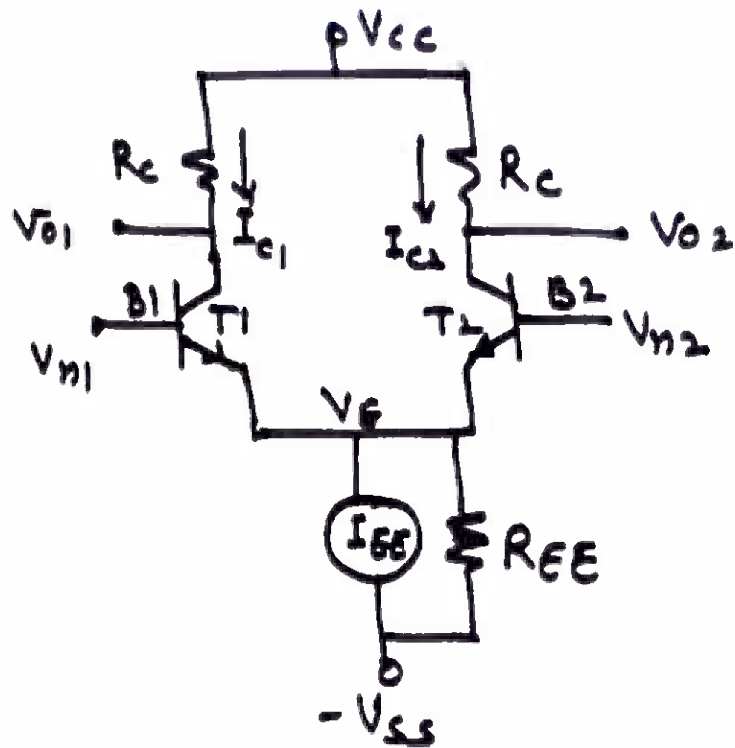


Bipolar Diffamp



$$V_{O1} - V_{O2} = V_{id}$$

Hence we apply

$$V_{in1} = \frac{V_{id}}{2} \quad \& \quad V_{in2} = -\frac{V_{id}}{2}$$

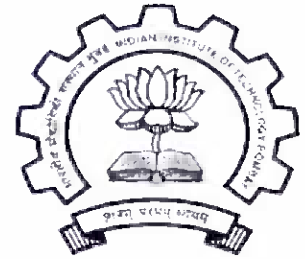
to keep $V_{id} = V_{in1} - V_{in2}$ intact.

T_1 has $\beta (g_m r_{\pi})$ which is same as for T_2

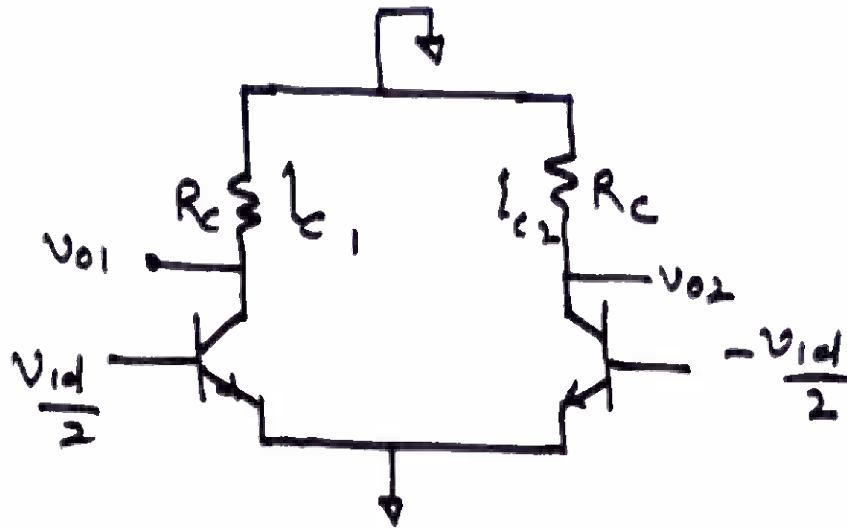


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AC circuit equivalent for BJT DIFFAMP in two Modes of Inputs is shown below:



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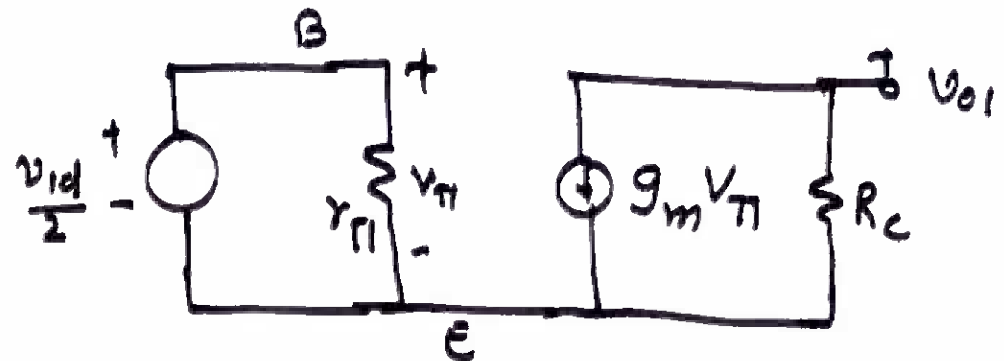


Difference Input

$$\text{Clearly } V_{\pi} = \frac{V_{id}}{2}$$

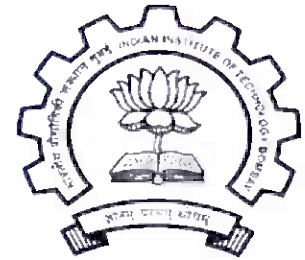
$$I_{c1} = \Delta I_c$$

$$I_{c2} = -\Delta I_c$$

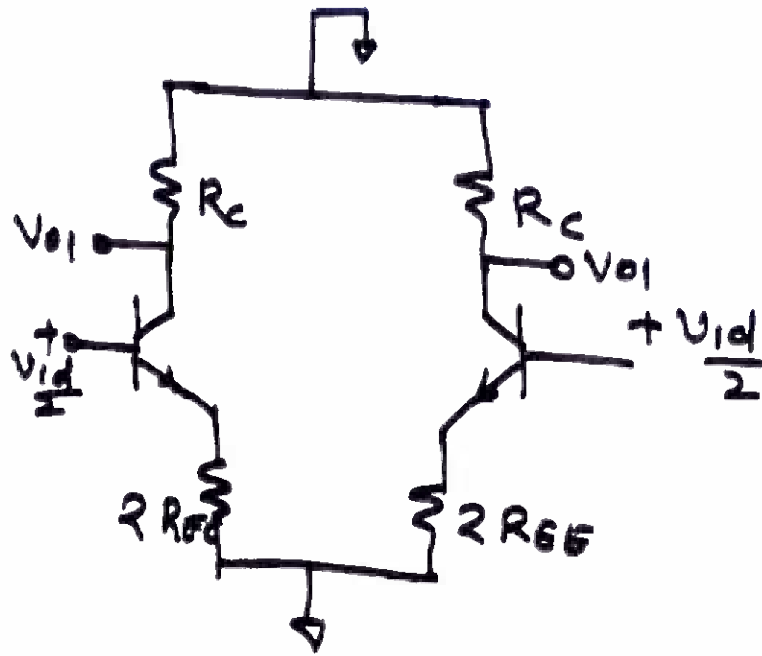


$$\therefore A_{vdd} = \frac{V_{o1}}{V_{id/2}} = \frac{-g_m V_{\pi} R_c}{V_{id/2}} = -g_m R_c$$

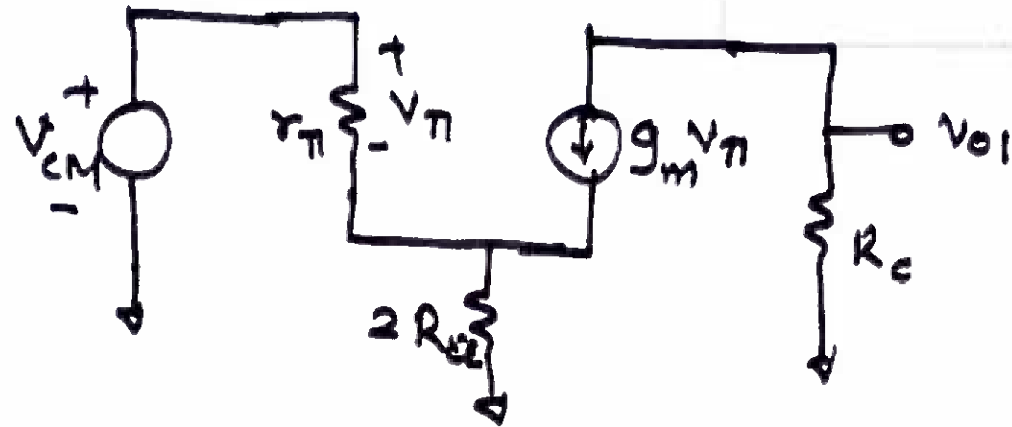
For Common Mode, the equ. ckt is



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$$V_{CM} = \frac{V_{id}}{2}$$



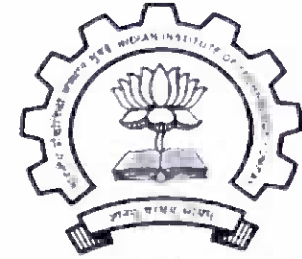
$$A_{VCM} = \frac{V_{O1}}{V_{CM}} = \frac{-\beta R_C}{r_{\pi} + 2R_{EE}(\beta + 1)} \approx \frac{-R_C}{2R_{EE}}$$

$$\therefore CMRR = \frac{A_{Vdd}}{A_{VCM}} =$$

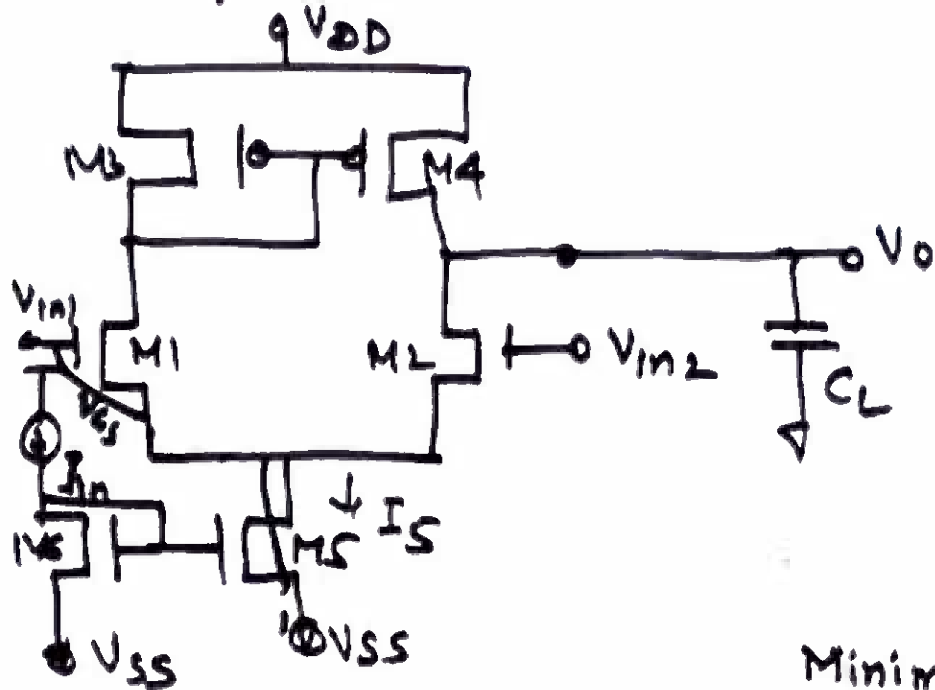
$$\frac{-g_m R_C}{1 + 2g_m R_{EE}} = 1 + 2g_m R_{EE}$$

If $R_{EE} \rightarrow \infty$ $CMRR \rightarrow \infty$
Else $CMRR$ is finite and around 80-120db

Current Mirror CMOS Diffamp.

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Example

Given $C_L = 5 \text{ pf}$ Slew Rate $\geq 10 \text{ V}/\mu\text{s}$. $V_{DD} = -V_{SS} = 2.5 \text{ V}$ $\beta_n' = 110 \mu\text{A}/\text{V}^2$, $\beta_p' = 50 \mu\text{A}/\text{V}^2$ $V_{tn} = 0.7 \text{ V} = |V_{tp}|$ $\lambda_n = 0.04/\text{V}$ & $\lambda_p = 0.05/\text{V}$

Minimum

frequency for Dominant Pole

 $\geq 100 \text{ kHz}$ (Bandwidth Minimum)

For Diffamp in DC case

$$I_{DS1} = I_{DS2} = \frac{I_S}{2}$$

CHOICE OF I_S

Slide No: 5

① From Maximum Power Dissipation of 1mW, we have

$$I_S (V_{DD} - V_{SS}) \leq 1 \text{ mW}$$

$$\text{or } I_S \leq \frac{1}{5} \times 10^{-3}$$

$$\therefore I_S \leq 200 \mu\text{A} \quad \text{--- PD requirement}$$

② Slew Rate $SR \geq 10 \text{ V}/\mu\text{s}$

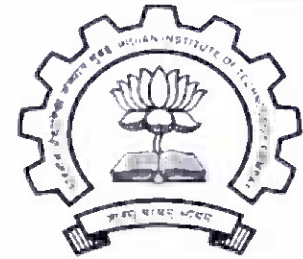
$$\text{Slew Rate} = SR = \frac{I_S}{C_L} \quad \text{or } I_S = SR \cdot C_L$$

$$\therefore I_S \geq 10 \times 10^6 \times 5 \times 10^{-12} \\ \geq 50 \mu\text{A}$$

③ We assume Dominant Pole (Bandwidth is due to heavy load capacitance $C_L = 5 \text{ pF}$)



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$$\text{or } f_{BW} = \frac{1}{2\pi R_{out} C_L}$$

$$\text{But } R_{out} = R_{o2} \parallel R_{o4} = \frac{1}{g_{o2} + g_{o4}}$$

$$= \frac{1}{\lambda_n \frac{I_{SS}}{2} + \lambda_p \frac{I_{SS}}{2}} = \frac{1}{(\lambda_n + \lambda_p) I_S / 2} = \frac{2}{(0.04 + 0.05) I_S} = \frac{22.22}{I_S}$$

$$\therefore \text{For } f_{BW} \geq 100 \text{ kHz}$$

$$100 \times 10^3 \geq \frac{I_S}{2\pi \times 22.22 \times 5 \times 10^{-12}}$$

$$\therefore I_S \geq 70 \mu\text{A}$$

To satisfy 'All THREE' Requirements

We choose $I_S = 100 \mu A$

$\therefore \frac{I_S}{2} = 50 \mu A$ In our further calculations of Gain

$$\text{Given } (W/L)_1 = (W/L)_2 = 18.4$$

$$\text{and } (W/L)_3 = (W/L)_4 = 8$$

$$\text{Then DC Gain} = g_{m1} R_{out} = \sqrt{\frac{2 \beta_n (W/L)_1 I_S / 2}{(\lambda_n + \lambda_p) I_S / 2}}$$

$$A_{vdo} = \frac{\sqrt{2 \times 110 \times 10^6 \times 18.4 \times 50 \times 10^{-6}}}{(0.09) \times \frac{100}{2} \times 10^{-6}} \approx 100$$



$$\text{Given } V_{ICM_{min}} = -1.5 \text{ V}$$

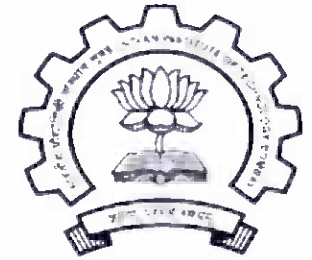
$$\therefore -1.5 = V_{Dsats} + V_{SS} + V_{GS1}$$

$$\text{or } V_{Dsats} = 1 - V_{GS1}$$

$$\begin{aligned} \text{But } V_{GS1} &= \sqrt{\frac{I_5/2}{\frac{1}{2} \beta_n' (W/L)_1}} + V_{TN} \\ &= \sqrt{\frac{2 \times 50 \times 10^{-6}}{1 \times 110 \times 10^{-6} \times 18.4}} + 0.7 \end{aligned}$$

$$\therefore V_{GS1} \cong 0.222 + 0.7 = 0.922 \text{ V}$$

$$\therefore V_{Dsats} = 1 - 0.922 \cong 0.08 \text{ V}$$



$$I_{S^-} = \frac{1}{2} \beta_n' (W/L)_S V_{DSat_S}^2$$

$$2 \times 100 \times 10^{-6} = 110 \times 10^{-6} (W/L)_S \times (0.08)^2$$

$$\therefore (W/L)_S \approx 300 \quad \text{Too high !!}$$



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